Zener Diode

DZ2S047×0L

Panasonic

DZ2S047×0L

Silicon epitaxial planar type

For constant voltage / For surge absorption circuit DZ2J047 in SSMini2 type package

■ Features

- · Excellent rising characteristics of zener current Iz
- · Low zener operating resistance Rz
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: AJ or AU

■ Packaging

Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

■ Absolute Maximum Ratings Ta = 25 °C

Parameter	Symbol	Rating	Unit
Repetitive peak forward current	IFRM	200	mA
Total power dissipation *1	PT	150	mW
Electrostatic discharge *2	ESD	±15	kV
Junction temperature	Tj	150	°C
Operating ambient temperature	Topr	-40 to +85	°C
Storage temperature	Tstg	-55 to +150	°C

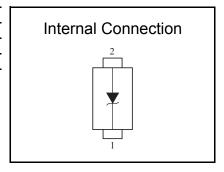
Note) *1 Mounted on glass epoxy print board ($45 \text{ mm} \times 45 \text{ mm} \times 1 \text{ mm}$) Solder in ($0.8 \text{ mm} \times 0.6 \text{ mm}$)

*2 Test method : IEC61000_4_2

(C = 150 pF, R = 330 Ω , Contact discharge : 10 times)

Unit: mm 0.8 0.13 2 2 1 0.3 1. Cathode 2. Anode

Panasonic	SSMini2-F5-B
JEITA	SC-79
Code	SOD-523



■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	VF	IF = 10 mA			1.0	V
Zener voltage *1, *2	VZ	IZ = 5 mA	4.47		4.94	V
Zener operating resistance	RZ	IZ = 5 mA			80	Ω
Zener rise operating resistance	RZK	IZ = 1 mA			800	Ω
Reverse current	IR	VR = 1 V			2.0	μΑ
Temperature coefficient of zener voltage *3	SZ	IZ = 5 mA		0.5		mV/°C

- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.
 - 2. Absolute frequency of input and output is 5 MHz.
 - 3. *1 The temperature must be controlled 25 °C for VZ mesurement. VZ value measured at other temperature must be adjusted to VZ (25 °C).
 - *2 VZ guaranted 20 ms after current flow

*3 Tj = 25 °C to 150 °C

Rank classification

Code	M			0			
Rank	M			No-rank			
VZ	4.59	to	4.83	4.47	to	4.94	
Marking symbol		ΑU			AJ		

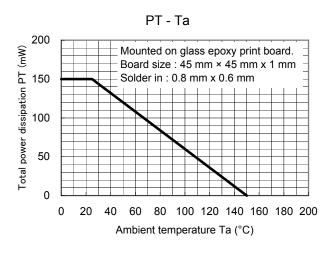
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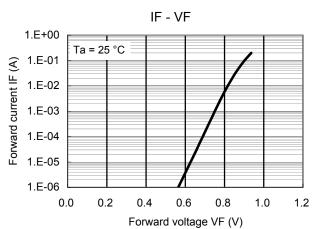
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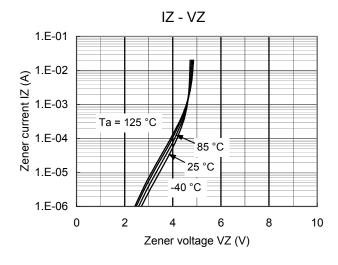
Zener Diode

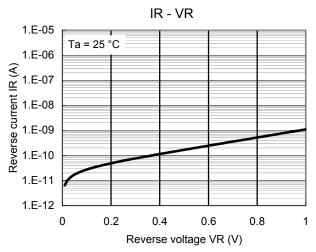
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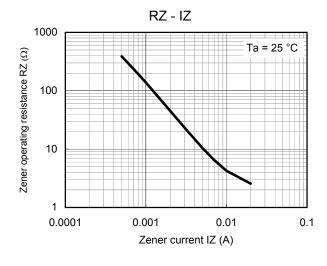
Technical Data (reference)

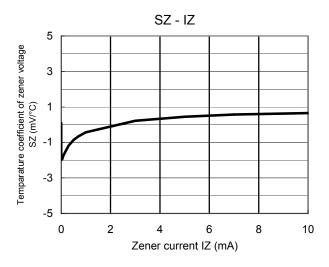










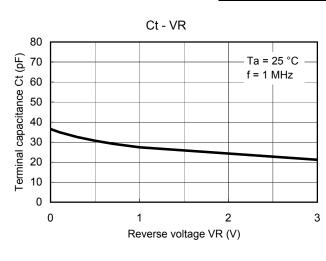


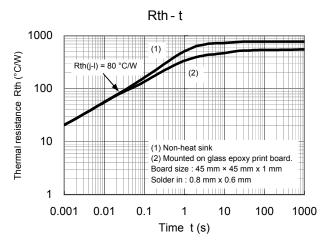
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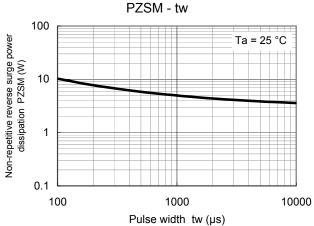
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Technical Data (reference)







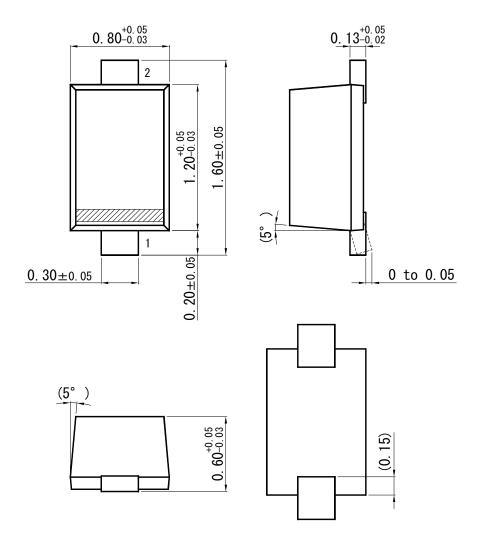
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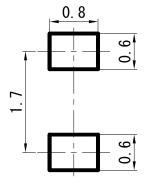
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SSMini2-F5-B

Unit: mm



■ Land Pattern (Reference) (Unit: mm)



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